NSN 5961-01-009-6316

No Fiig: A110a0



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-009-6316 **Inclosure Material:** Metal **Overall Length:** 0.078 inches **Overall Height:** 0.033 inches **Overall Width:** 0.042 inches **Internal Configuration:** Junction contact **Internal Junction Configuration:** Pnp **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 45.0 breakdown voltage, collector-to-base, emitter open and 30.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 300.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 360.0 milliwatts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 165.0 degrees celsius junction **Precious Material And Location:** Landsurface gold **Precious Material: Terminal Type And Quantity:** 4 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**